SD1019-2

ROHS Compliance, Silicon NPN POWER TRANSISTOR

DESCRIPTION:

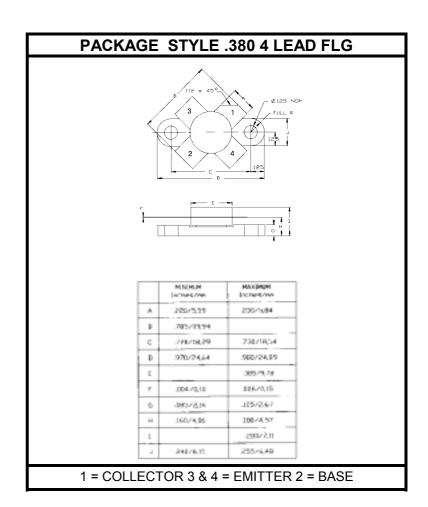
The **HG SD1019-2** is Designed for VHF Communications up to 136 MHz

FEATURES:

P_G = 4.5 dB Minimum at 150 MHz *Omnigold*™ Metallization System

MAXIMUM RATINGS

Ic	9.0 A
V _{CB}	65 V
V _{CE}	35 V
P _{DISS}	117 W @ T_C = 25 $^{\circ}$ C
Τ _J	-65 °C to +200 °C
T _{STG}	-65 °C to +150 °C
JC	1.7 °C/W



CHARACTERISTICS T_C = 25 °C

SYMBOL	TEST CONDITIONS			MINIMUM	TYPICAL	MAXIMUM	UNITS
BV _{CBO}	I _C = 20 mA			65			٧
BV _{CEO}	I _C = 200 mA			35			٧
BV _{EBO}	I _E = 10 mA			4.0			٧
I _{CBO}	V _{CB} = 30 V				1.5		mA
h _{FE}	V _{CE} = 5.0 V	$I_C = 500 \text{ mA}$		5.0			
Сов	V _{CB} = 30 V		f = 1.0 MHz			150	pF
Р _{оит} РG	V _{CC} = 13.5 V	P _{IN} = 10.6 W	f = 150 MHz	30 4.5			W dB

Note : Above parameters , ratings , limits and conditions are subject to change .

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